# NSN 5961-00-836-8519

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.260 inches

# Terminal Length:

1.500 inches

# **Overall Diameter:**

0.370 inches

#### Internal Configuration:

Junction contact

#### Mounting Method:

Terminal

### **Terminal Circle Diameter:**

0.100 inches

#### Features Provided:

### Hermetically sealed case

### **Criticality Code Justification:**

Feat

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 35.0

breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 5.2 breakdown voltage, emitter-to-base, collector open

### **Current Rating Per Characteristic:**

Between 600.00 milliamperes source cutoff current and 1.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

600.0 milliwatts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### **Nuclear Hardness Critical Feature:**

Hardened

### **Precious Material And Location:**

Terminal surface gold

### **Precious Material:**

Gold

### **Terminal Type And Quantity:**

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

